- 5 A Continuous On-State Current
- 30 A Surge-Current
- Glass Passivated Wafer
- 400 V to 800 V Off-State Voltage
- Max I<sub>GT</sub> of 200 μA

# TO-220 PACKAGE (TOP VIEW) K 1 A 2 G 3

Pin 2 is in electrical contact with the mounting base.

MDC1ACA

#### absolute maximum ratings over operating case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT	
	TIC106D		400		
Repetitive peak off-state voltage (see Note 1)	TIC106M	V	600	V	
	TIC106S	$V_{DRM}$	700		
	TIC106N		800		
	TIC106D		400	٧	
Repetitive peak reverse voltage	TIC106M	V	600		
	TIC106S	$V_{RRM}$	700		
	TIC106N		800		
Continuous on-state current at (or below) 80°C case temperature (see Note 2)		I <sub>T(RMS)</sub>	5	Α	
Average on-state current (180° conduction angle) at (or below) 80°C case temperature		L	3.2	А	
(see Note 3)		I <sub>T(AV)</sub>	0.2		
Surge on-state current at (or below) 25°C (see Note 4)		I <sub>TSM</sub>	30	Α	
Peak positive gate current (pulse width ≤ 300 μs)		I <sub>GM</sub>	0.2	Α	
Peak gate power dissipation (pulse width ≤ 300 μs)		P <sub>GM</sub>	1.3	W	
Average gate power dissipation (see Note 5)		P <sub>G(AV)</sub>	0.3	W	
Operating case temperature range		T <sub>C</sub>	-40 to +110	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +125	°C	
Lead temperature 1.6 mm from case for 10 seconds		T <sub>L</sub>	230	°C	

NOTES: 1. These values apply when the gate-cathode resistance  $R_{GK}$  = 1  $k\Omega$ 

- 2. These values apply for continuous dc operation with resistive load. Above 80°C derate linearly to zero at 110°C.
- 3. This value may be applied continuously under single phase 50 Hz half-sine-wave operation with resistive load. Above 80°C derate linearly to zero at 110°C.
- 4. This value applies for one 50 Hz half-sine-wave when the device is operating at (or below) the rated value of peak reverse voltage and on-state current. Surge may be repeated after the device has returned to original thermal equilibrium.
- 5. This value applies for a maximum averaging time of 20 ms.



#### electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER		TEST CONDITIO	ONS	MIN	TYP	MAX	UNIT
I <sub>DRM</sub>	Repetitive peak off-state current	V <sub>D</sub> = rated V <sub>DRM</sub>	R <sub>GK</sub> = 1 kΩ	T <sub>C</sub> = 110°C			400	μА
I <sub>RRM</sub>	Repetitive peak reverse current	V <sub>R</sub> = rated V <sub>RRM</sub>	I <sub>G</sub> = 0	T <sub>C</sub> = 110°C			1	mA
I <sub>GT</sub>	Gate trigger current	V <sub>AA</sub> = 12 V	$R_L = 100 \Omega$	t <sub>p(g)</sub> ≥ 20 μs		5	200	μΑ
V <sub>GT</sub> Gate trigger v		$V_{AA} = 12 \text{ V}$ $t_{p(g)} \ge 20  \mu\text{s}$	$R_L = 100 \Omega$ $R_{GK} = 1 k\Omega$	T <sub>C</sub> = - 40°C			1.2	
	Gate trigger voltage	$V_{AA} = 12 \text{ V}$ $t_{p(g)} \ge 20  \mu\text{s}$	$R_L = 100 \Omega$ $R_{GK} = 1 k\Omega$		0.4	0.6	1	V
		$V_{AA} = 12 \text{ V}$ $t_{p(g)} \ge 20  \mu\text{s}$	$R_L = 100 \Omega$ $R_{GK} = 1 k\Omega$	T <sub>C</sub> = 110°C	0.2			
I <sub>H</sub> I	Holding current	$V_{AA} = 12 \text{ V}$ Initiating $I_T = 10 \text{ mA}$	$R_{GK} = 1 k\Omega$	T <sub>C</sub> = - 40°C			8	mA
		$V_{AA} = 12 \text{ V}$ Initiating $I_T = 10 \text{ mA}$	$R_{GK} = 1 k\Omega$				5	
V <sub>T</sub>	Peak on-state voltage	I <sub>T</sub> = 5 A	(See Note 6)				1.7	V
dv/dt	Critical rate of rise of off-state voltage	V <sub>D</sub> = rated V <sub>D</sub>	R <sub>GK</sub> = 1 kΩ	T <sub>C</sub> = 110°C		10		V/µs

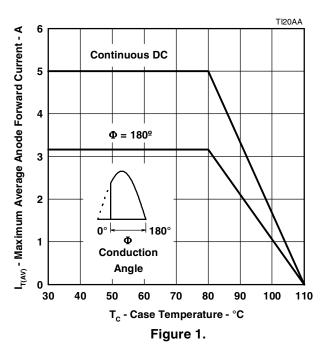
NOTE 6: This parameter must be measured using pulse techniques, t<sub>p</sub> = 300 µs, duty cycle ≤ 2 %. Voltage sensing-contacts, separate from the current carrying contacts, are located within 3.2 mm from the device body.

#### thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			3.5	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

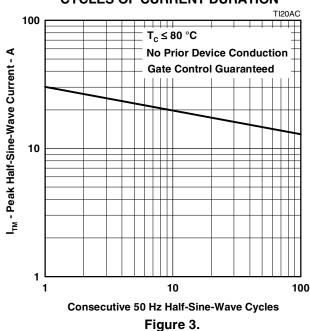
#### THERMAL INFORMATION

## AVERAGE ANODE ON-STATE CURRENT DERATING CURVE

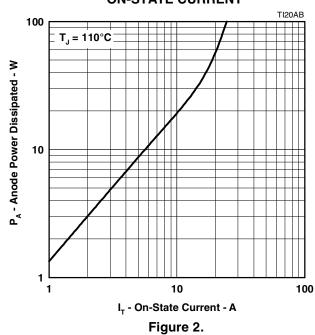


## SURGE ON-STATE CURRENT

#### **CYCLES OF CURRENT DURATION**



# ANODE POWER DISSIPATED vs ON-STATE CURRENT



## TRANSIENT THERMAL RESISTANCE vs

#### **CYCLES OF CURRENT DURATION**

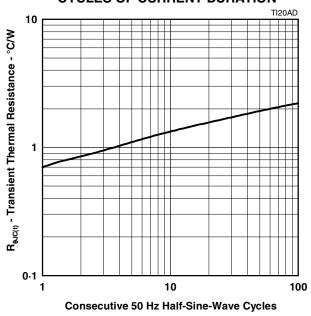
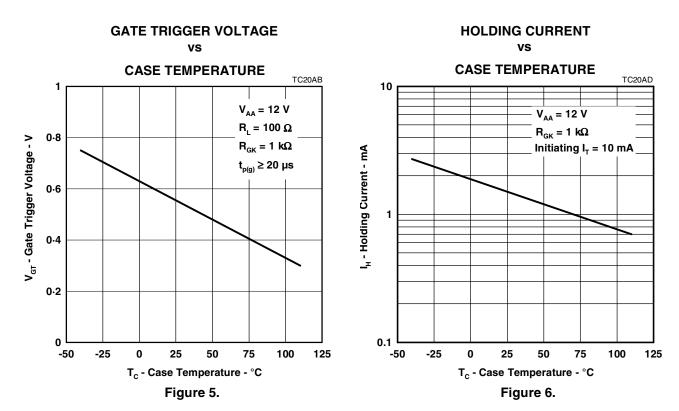


Figure 4.

#### PRODUCT INFORMATION

#### TYPICAL CHARACTERISTICS



## PEAK ON STATE CURRENT

